NSN 5961-00-476-6346

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View Online at https://aerobasegroup.com/nsn/5961-00-476-6346 **Inclosure Material:** Ceramic or glass or metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 0.165 inches **Overall Height:** 0.063 inches **Overall Width:** Between 0.140 inches and 0.260 inches **Function For Which Designed:** Switching **Component Name And Quantity:** 8 semiconductor device diode **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 40.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 350.00 milliamperes forward current, average absolute all semiconductor device diode **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Precious Material And Location:** Terminals gold **Precious Material:** Gold **Terminal Type And Quantity:** 10 ribbon Shelf Life: N/a **Unit Of Measure:**

No

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